2SD2255

Silicon NPN triple diffusion planar type Darlington

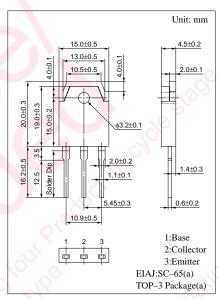
For power amplification Complementary to 2SB1493

Features

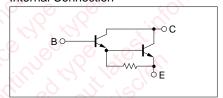
- Optimum for 60W HiFi output
- High foward current transfer ratio h_{FE}: 5000 to 30000
- Low collector to emitter saturation voltage V_{CE(sat)}: <2.5V

Absolute Maximum Ratings (T_C=25°C)

Symbol	Ratings	Unit
V _{CBO}	160	V
V _{CEO}	140	V
V _{EBO}	5	V
I_{CP}	12	A
I_{C}	7	A
D	70	W.
P_{C}	2.5	W
Tj	150	°C
$T_{\rm stg}$	-55 to +150	O °C
	V_{CBO} V_{CEO} V_{EBO} I_{CP} I_{C} I_{C} T_{j}	$\begin{array}{c cccc} V_{CBO} & 160 \\ \hline V_{CEO} & 140 \\ \hline V_{EBO} & 5 \\ \hline I_{CP} & 12 \\ \hline I_{C} & 7 \\ \hline P_{C} & 70 \\ \hline 2.5 \\ \hline T_{j} & 150 \\ \hline \end{array}$



Internal Connection



Electrical Characteristics (T_C=25°C)

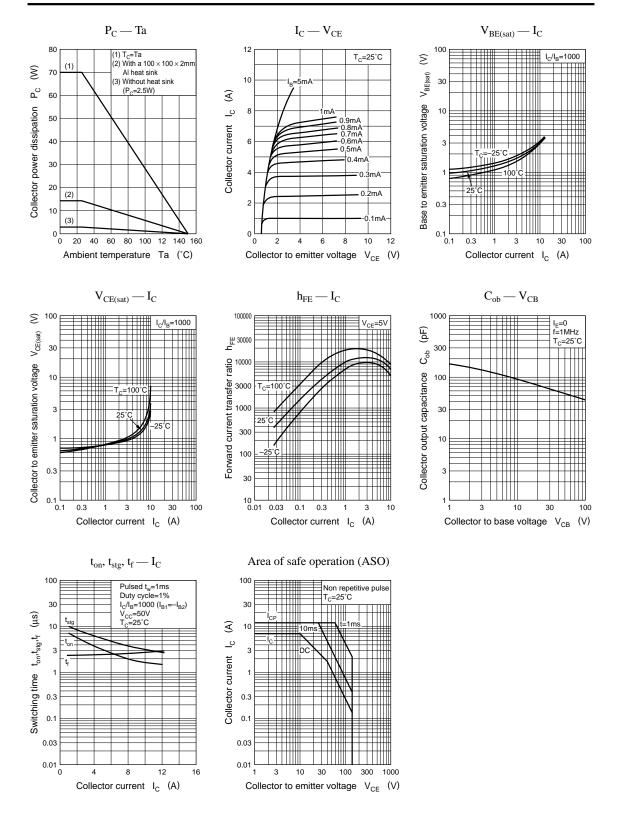
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 160V, I_E = 0$			100	μA
	I_{CEO}	$V_{CE} = 140V, I_B = 0$	25		100	μΑ
Emitter cutoff current	I_{EBO}	$V_{EB} = 5V, I_{C} = 0$			100	μΑ
Collector to emitter voltage	V _{CEO}	$I_C = 30 \text{mA}, I_B = 0$	140			V
To a second	h _{FE1}	$V_{CE} = 5V, I_{C} = 1A$	2000			
Forward current transfer ratio	h _{FE2} *	$V_{CE} = 5V$, $I_C = 6A$	5000		30000	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = 6A, I_B = 6mA$			2.5	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_C = 6A, I_B = 6mA$			3.0	V
Transition frequency	f_T	$V_{CE} = 10V, I_{C} = 0.5A, f = 1MHz$		20		MHz
Turn-on time	t _{on}	I CA I COLA I COLA		2.5		μs
Storage time	t _{stg}	$I_C = 6A, I_{B1} = 6mA, I_{B2} = -6mA,$ $V_{CC} = 50V$		5.0		μs
Fall time	t _f			2.5		μs

*h_{FE2} Rank classification

Rank	Q	P
h _{FE2}	5000 to 15000	8000 to 30000

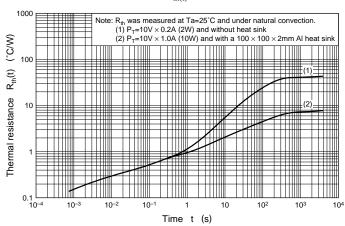
Panasonic

Power Transistors 2SD2255



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